TOSHIBA Photocoupler Photo Relay

# TLP798GA

**Telecommunication** 

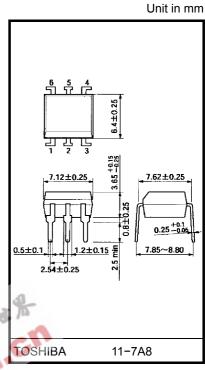
**Data Acquisition** 

Measurement Instrumentation

The TOSHIBA TLP798GA consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo–MOS FET in a six lead plastic DIP package (DIP6).

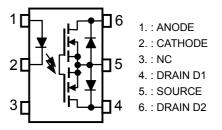
The TLP798GA is a bi-directional switch which can replace mechanical relays in many applications.

- Peak off-state voltage: 400 V (min.)
- On-state current: 150 mA (max.) (A connection)
- On-state resistance:  $12 \Omega$  (max.) (A connection)
- Isolation voltage: 5000 Vrms (min.) (A connection)
- Isolation Thickness: 0.4 mm (min.)

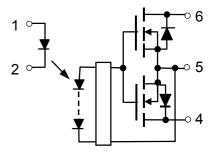


Weight: 0.4 g

### Pin Configuration (top view)



#### **Schematic**



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#### Absolute Maximum Ratings (Ta = 25°C)

Characteristic			Symbol	Rating	Unit	
	Forward current	Ι <sub>F</sub>	30	mA		
	Forward current derating (Ta ≥ 25°C)		ΔI <sub>F</sub> / °C	-0.3	mA / °C	
ED	Peak forward current (100 µs pulse, 100 pps	s)	I <sub>FP</sub>	1	Α	
_	Reverse voltage		V <sub>R</sub>	5	V	
	Junction temperature	Tj	125	°C		
	Off-state output terminal voltage		V <sub>OFF</sub>	400	V	
	On-state RMS current	A connection	lon	150	mA / °C	
		B connection		200		
ctor		C connection		300		
Detector	On–state current derating (Ta ≥ 25°C)	A connection	Δl <sub>ON</sub> / °C	-1.5		
		B connection		-2.0		
		C connection		-3.0	1	
	Junction temperature	Tj	125	°C		
Storage temperature range			T <sub>stg</sub>	-55~125	°C	
Oper	ating temperature range	T <sub>opr</sub>	-40~85	°C		
Lead	soldering temperature (10 s)	T <sub>sol</sub>	260	°C		
Isolat	tion voltage (AC, 1 min., R.H. ≤ 60%)	BVS	5000	Vrms		

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

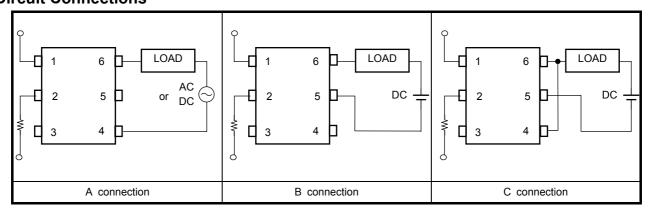
(Note 2): Device considered a two–terminal device: Pins 1, 2 and 3 shorted together, and pins 4, 5 and 6 shorted together.

#### **Recommended Operating Conditions**

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	$V_{DD}$	_	_	320	V
Forward current	lF	5	7.5	20	mA
On-state current (A connection)	I <sub>ON</sub>	_	_	150	mA
Operating temperature	T <sub>opr</sub>	-20	_	80	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

#### **Circuit Connections**



## Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 10 mA	1.18	1.33	1.48	V
LED	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 5 V	_	_	10	μΑ
	Capacitance	C <sub>T</sub>	V = 0, f = 1 MHz	_	30		pF
ector	Off–state current	l <sub>OFF</sub>	V <sub>OFF</sub> = 400 V	_	_	1	μΑ
Detector	Capacitance	C <sub>OFF</sub>	V = 0, f = 1 MHz		_	_	pF

## **Coupled Electrical Characteristics (Ta = 25°C)**

Characteristic		Symbol	Test Condition	Min.	Тур.	Max.	Unit
Trigger LED current		I <sub>FT</sub>	I <sub>ON</sub> = 150 mA	_	1	3	mA
	A connection	+	I <sub>ON</sub> = 150 mA, I <sub>F</sub> = 5 mA	_	8	12	
On-state resistance	B connection		I <sub>ON</sub> = 200 mA, I <sub>F</sub> = 5 mA	_	4	6	Ω
	C connection		I <sub>ON</sub> = 300 mA, I <sub>F</sub> = 5 mA		2	3	

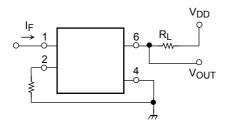
## **Isolation Characteristics (Ta = 25°C)**

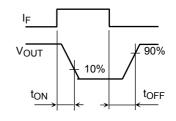
olation Characteristics (	Га = 25°C)	4,18	A.			
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance input to output	CS	$V_S = 0$ , $f = 1$ MHz	_	0.8	_	pF
Isolation resistance	Rs	V <sub>S</sub> = 500 V, R.H. ≤ 60%	5 × 10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
		AC, 1 minute	5000	_	_	Vrms
Isolation voltage	BVS	AC, 1 second (in oil)	_	10000	_	VIIIIS
		DC, 1 minute (in oil)	_	10000	_	$V_{DC}$

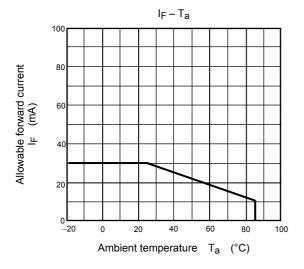
# Switching Characteristics (Ta = 25°C)

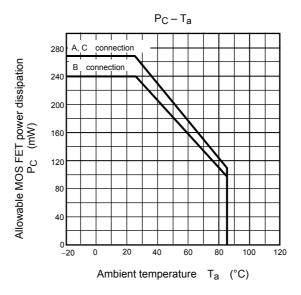
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Turn-on time	t <sub>ON</sub>	$V_{DD}$ = 20 V, $R_L$ = 200 $\Omega$	_	0.3	1.0	ms
Turn-off time	toff	$I_F = 5 \text{ mA}$ (Note 3)	-	0.2	1.0	1113

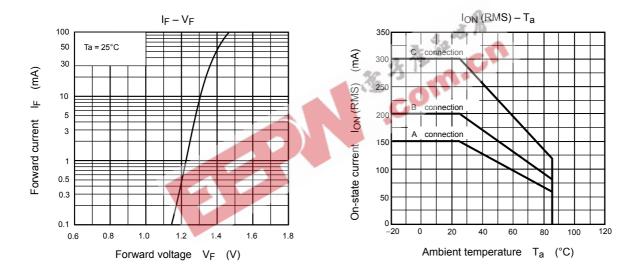
(Note 3): Switching time test circuit



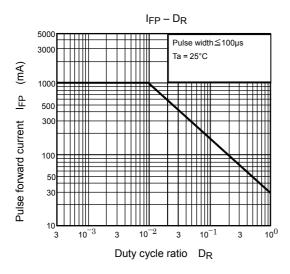








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